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### Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	27696
Total RAM Bits	1130496
Number of I/O	138
Number of Gates	-
Voltage - Supply	1.14V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-LFBGA
Supplier Device Package	256-FPBGA (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/m2gl025t-1vf256">https://www.e-xfl.com/product-detail/microchip-technology/m2gl025t-1vf256</a>

## 1.9 Revision 3.0

In revision 3.0 of this document, the Theta B/C columns and FCS325 package was updated. For more information, see Table 9, page 10 (SAR 62002).

## 1.10 Revision 2.0

The following is a summary of the changes in revision 2.0 of this document.

- Table 1, page 4 was updated (SAR 59056).
- Table 7, page 8 temperature and data retention information was updated SAR (61363).
- Storage Operating Table was updated and split into three tables – Table 5, page 7, Table 7, page 8 (SAR 58725).
- Updated Theta B/C columns and FCS325 package in Table 9, page 10 (SAR 62002).
- Added 090-FCS325 thermal resistance to Table 9, page 10 (SAR 59384).
- TQ144 package was added to Table 9, page 10 (SAR 57708).
- Added PLL jitter data for the VF400 package (SAR 53162).
- Added Additional Worst Case IDD to Table 11, page 12 and Table 12, page 13 (SAR 59077).
- Table 13, page 13, Table 14, page 13, and Table 15, page 14 were added to verify Inrush currents (SAR 56348).
- Table 18, page 19 and Table 21, page 20 – I/O speeds were replaced.
- Max speed was changed in Table 41, page 26 (SAR 57221) and in Table 52, page 29 (SAR 57113).
- Minimum and Maximum DC/AC Input and Output Levels Specification, page 29 and Table 49, page 29–Table 57, page 31 were added.
- Added Cload to Table 89, page 39 (SAR 56238).
- Removed "Rs" information in DDR Timing Measurement Table 123, page 47, Table 133, page 49, and Table 144, page 52.
- Updated drive programming for M/B-LVDS outputs (SAR 58154).
- Added an inverter bubble to DDR\_IN latch in Figure 10, page 70 (SAR 61418).
- QF waveform in Figure 11, page 71 was updated (SAR 59816).
- uSRAM Write Clock minimum values were updated in Table 237, page 86–Table 243, page 93 (SAR 55236).
- Fixed typo in the 32 kHz Crystal (XTAL) oscillator accuracy data section (SAR 59669).
- The "On-Chip Oscillator" section was split, and the Embedded NVM (eNVM) Characteristics, page 104 was added. Table 277, page 107–Table 281, page 109 were revised.(SARs 57898 and 59669).
- PLL VCP Frequency and conditions were added to Table 282, page 110 (SAR 57416).
- Fixed typo for PLL jitter data in the 100-400 MHz range (SAR 60727).
- Updated FCCC information in Table 282, page 110 and Table 283, page 111 (SAR 60799).
- Device 025 specifications were added to Table 283, page 111 (SAR 51625).
- JTAG Table 284, page 112 was replaced (SAR 51188).
- Flash\*Freeze Table 293, page 119 was replaced (SAR 57828).
- Added support for HCSL I/O Standard for SERDES reference clocks in Table 300, page 123 and Table 301, page 123 (SAR 50748).
- Tir and Tif parameters were added to Table 303, page 124 (SAR 52203).
- Speed grade consistency was fixed in tables throughout the datasheet (SAR 50722).
- Added jitter attenuation information (SAR 59405).

## 1.11 Revision 1.0

The following is a summary of the changes in revision 1.0 of this document.

- The IGLOO2 v2 and the SmartFusion2 v5 datasheets are combined into this single product family datasheet.

**Figure 1 • High Temperature Data Retention (HTR)****2.3.1.1 Overshoot/Undershoot Limits**

For AC signals, the input signal may undershoot during transitions to  $-1.0$  V for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

For AC signals, the input signal may overshoot during transitions to  $V_{CC1} + 1.0$  V for no longer than 10% of the period. The current during the transition must not exceed 100 mA.

**Note:** The above specifications do not apply to the PCI standard. The IGLOO2 and SmartFusion2 PCI I/Os are compliant with the PCI standard including the PCI overshoot/undershoot specifications.

**2.3.1.2 Thermal Characteristics**

The temperature variable in the Microsemi SoC Products Group Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption causes the chip's junction temperature to be higher than the ambient, case, or board temperatures.

EQ1 through EQ3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - T_A}{P}$$

EQ 1

$$\theta_{JB} = \frac{T_J - T_B}{P}$$

EQ 2

$$\theta_{JC} = \frac{T_J - T_C}{P}$$

EQ 3

**Table 15 • Inrush Currents at Power up,  $-40\text{ }^{\circ}\text{C} \leq T_J \leq 100\text{ }^{\circ}\text{C}$  – Typical Process**

Power Supplies	Voltage (V)	005	010	025	050	060	090	150	Unit
$V_{DD}$	1.26	25	32	38	48	45	77	109	mA
$V_{PP}$	3.46	33	49	36	180	13	36	51	mA
$V_{DDI}$	2.62	134	141	161	187	93	272	388	mA
Number of banks		7	8	8	10	10	9	19	

### 2.3.3 Average Fabric Temperature and Voltage Derating Factors

The following table lists the average temperature and voltage derating factors for fabric timing delays normalized to  $T_J = 85\text{ }^{\circ}\text{C}$ , in worst-case  $V_{DD} = 1.14\text{ V}$ .

**Table 16 • Average Junction Temperature and Voltage Derating Factors for Fabric Timing Delays**

Array Voltage $V_{DD}$ (V)	$-40\text{ }^{\circ}\text{C}$	$0\text{ }^{\circ}\text{C}$	$25\text{ }^{\circ}\text{C}$	$70\text{ }^{\circ}\text{C}$	$85\text{ }^{\circ}\text{C}$	$100\text{ }^{\circ}\text{C}$
1.14	0.83	0.89	0.92	0.98	<b>1.00</b>	1.02
1.2	0.75	0.80	0.83	0.89	0.91	0.93
1.26	0.69	0.73	0.76	0.81	0.83	0.85

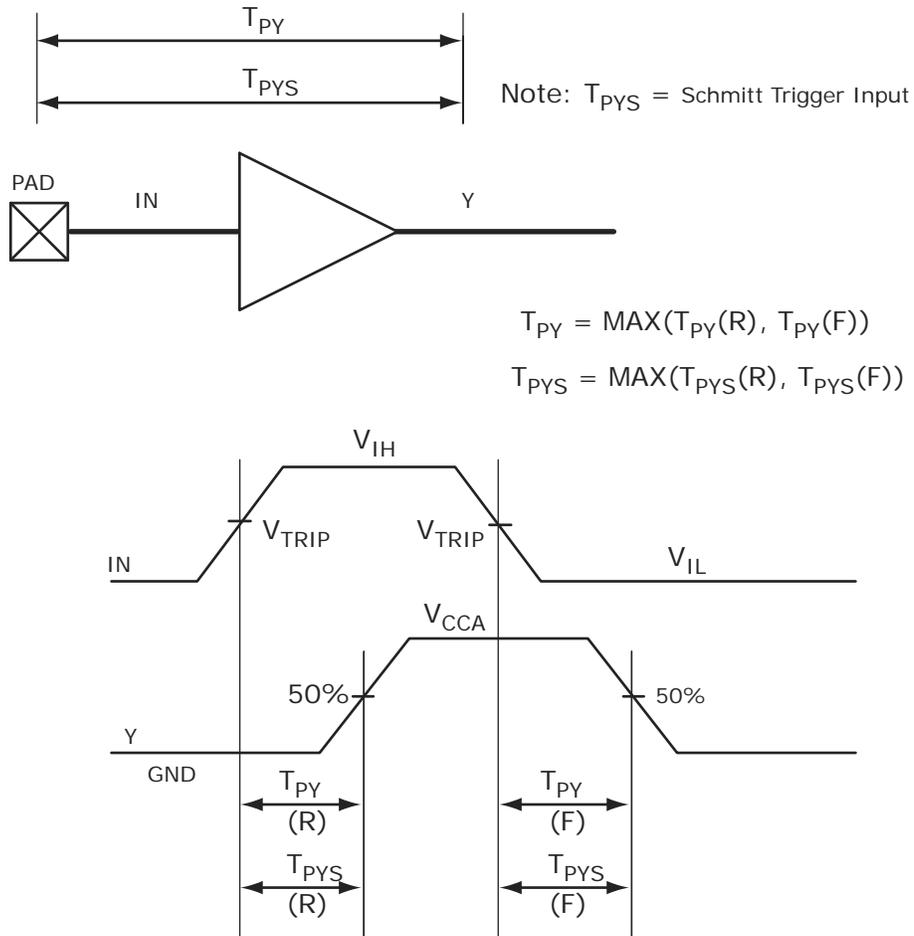
## 2.3.5 User I/O Characteristics

There are three types of I/Os supported in the IGLOO2 FPGA and SmartFusion2 SoC FPGA families: MSIO, MSIOD, and DDRIO I/O banks. The I/O standards supported by the different I/O banks is described in the I/Os section of the *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide*.

### 2.3.5.1 Input Buffer and AC Loading

The following figure shows the input buffer and AC loading.

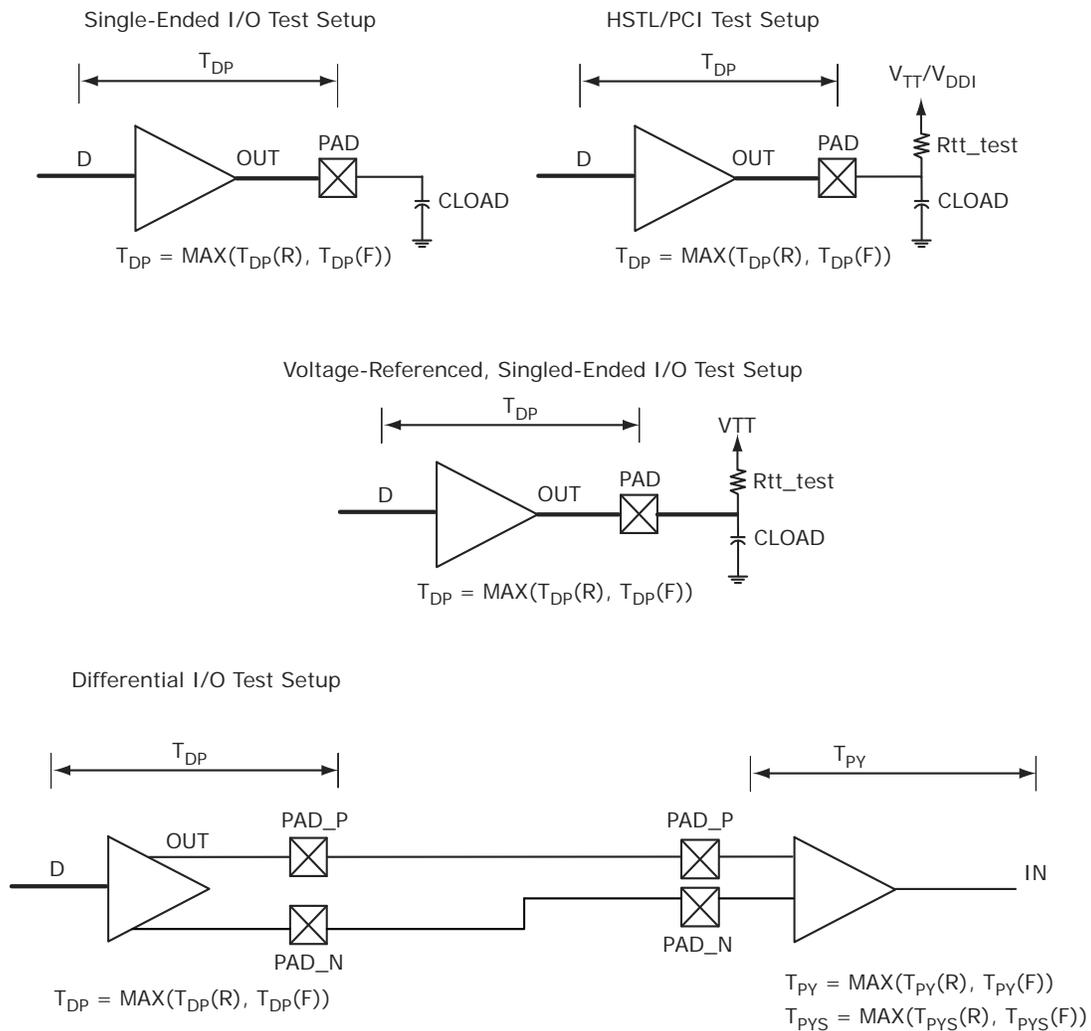
**Figure 3 • Input Buffer AC Loading**



### 2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

**Figure 4 • Output Buffer AC Loading**



**Table 70 • LVCMOS 1.5 V Transmitter Characteristics for DDRIO I/O Bank (Output and Tristate Buffers)**  
(continued)

Output Drive Selection	Slew Control	T <sub>DP</sub>		T <sub>ZL</sub>		T <sub>ZH</sub>		T <sub>HZ</sub> <sup>1</sup>		T <sub>LZ</sub> <sup>1</sup>		Unit
		-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	
6 mA	Slow	4.244	4.993	3.465	4.076	4.233	4.979	6.39	7.518	5.736	6.748	ns
	Medium	3.774	4.44	3.05	3.587	3.762	4.426	6.114	7.193	5.397	6.35	ns
	Medium fast	3.544	4.17	2.839	3.339	3.529	4.152	5.978	7.033	5.27	6.2	ns
	Fast	3.519	4.14	2.82	3.317	3.504	4.122	5.965	7.017	5.259	6.187	ns
8 mA	Slow	4.099	4.823	3.311	3.894	4.087	4.807	6.584	7.746	5.854	6.888	ns
	Medium	3.656	4.301	2.927	3.443	3.642	4.284	6.311	7.425	5.553	6.533	ns
	Medium fast	3.437	4.044	2.731	3.213	3.42	4.023	6.182	7.273	5.435	6.394	ns
	Fast	3.41	4.012	2.715	3.193	3.393	3.991	6.178	7.269	5.425	6.383	ns
10 mA	Slow	4.029	4.74	3.238	3.809	4.015	4.723	6.732	7.921	5.965	7.018	ns
	Medium	3.601	4.237	2.867	3.372	3.586	4.218	6.473	7.615	5.669	6.669	ns
	Medium fast	3.384	3.981	2.672	3.143	3.365	3.958	6.351	7.471	5.55	6.529	ns
	Fast	3.357	3.949	2.655	3.123	3.338	3.927	6.345	7.464	5.54	6.518	ns
12 mA	Slow	3.974	4.675	3.196	3.759	3.958	4.656	6.842	8.049	6.068	7.139	ns
	Medium	3.55	4.176	2.827	3.326	3.534	4.157	6.584	7.746	5.751	6.766	ns
	Medium fast	3.345	3.935	2.638	3.103	3.325	3.911	6.488	7.633	5.641	6.637	ns
	Fast	3.316	3.902	2.621	3.083	3.297	3.878	6.486	7.63	5.626	6.619	ns

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 71 • LVCMOS 1.5 V Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)**

Output Drive Selection	Slew Control	T <sub>DP</sub>		T <sub>ZL</sub>		T <sub>ZH</sub>		T <sub>HZ</sub> <sup>1</sup>		T <sub>LZ</sub> <sup>1</sup>		Unit
		-1	-Std	-1	-Std	-1	-Std	-1	-Std	-1	-Std	
2 mA	Slow	4.423	5.203	5.397	6.35	5.686	6.69	5.609	6.599	5.561	6.542	ns
4 mA	Slow	4.05	4.765	4.503	5.298	4.92	5.788	7.358	8.657	6.525	7.677	ns
6 mA	Slow	4.081	4.801	4.259	5.012	4.699	5.528	7.659	9.011	6.709	7.893	ns
8 mA	Slow	4.234	4.98	4.068	4.786	4.521	5.319	8.218	9.668	7.05	8.294	ns

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

**Table 128 • DDR2/SSTL18 Transmitter Characteristics (Output and Tristate Buffers)**

	$T_{DP}$		$T_{ZL}$		$T_{ZH}$		$T_{HZ}$		$T_{LZ}$		Unit
	-1	-Std									
<b>SSTL18 Class I (for DDRIO I/O Bank)</b>											
Single-ended	2.383	2.804	2.23	2.623	2.229	2.622	2.202	2.591	2.201	2.59	ns
Differential	2.413	2.84	2.797	3.29	2.797	3.29	2.282	2.685	2.282	2.685	ns
<b>SSTL18 Class II (for DDRIO I/O Bank)</b>											
Single-ended	2.281	2.683	2.196	2.584	2.195	2.583	2.171	2.555	2.17	2.554	ns
Differential	2.315	2.724	2.698	3.173	2.698	3.173	2.242	2.639	2.242	2.639	ns

**2.3.6.5 Stub-Series Terminated Logic 1.5 V (SSTL15)**

SSTL15 Class I and Class II are supported in IGLOO2 FPGAs and SmartFusion2 SoC FPGAs, and also comply with the reduced and full drive double data rate (DDR3) standard. IGLOO2 FPGA and SmartFusion2 SoC FPGA I/Os supports both standards for single-ended signaling and differential signaling for SSTL18. This standard requires a differential amplifier input buffer and a push-pull output buffer.

**Minimum and Maximum DC/AC Input and Output Levels Specification**

The following table lists the SSTL15 DC voltage specifications for DDRIO bank.

**Table 129 • SSTL15 DC Recommended DC Operating Conditions (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	$V_{DDI}$	1.425	1.5	1.575	V
Termination voltage	$V_{TT}$	0.698	0.750	0.803	V
Input reference voltage	$V_{REF}$	0.698	0.750	0.803	V

**Table 130 • SSTL15 DC Input Voltage Specification (for DDRIO I/O Bank Only)**

Parameter	Symbol	Min	Max	Unit
DC input logic high	$V_{IH}(DC)$	$V_{REF} + 0.1$	1.575	V
DC input logic low	$V_{IL}(DC)$	-0.3	$V_{REF} - 0.1$	V
Input current high <sup>1</sup>	$I_{IH}(DC)$			
Input current low <sup>1</sup>	$I_{IL}(DC)$			

1. See Table 24, page 22.

**Table 159 • LPDDR-LVCMOS 1.8 V AC Switching Characteristics for Transmitter for DDRIO I/O Bank (Output and Tristate Buffers) (continued)**

	medium	3.246	3.819	2.686	3.16	3.236	3.807	5.542	6.52	4.936	5.807	ns
	medium_fast	3.066	3.607	2.525	2.971	3.054	3.593	5.405	6.359	4.811	5.66	ns
	fast	3.046	3.584	2.513	2.957	3.034	3.57	5.401	6.353	4.803	5.651	ns
10 mA	slow	3.498	4.115	2.878	3.386	3.481	4.096	6.046	7.113	5.444	6.404	ns
	medium	3.138	3.692	2.569	3.023	3.126	3.678	5.782	6.803	5.129	6.034	ns
	medium_fast	2.966	3.489	2.414	2.841	2.951	3.472	5.666	6.665	5.013	5.897	ns
	fast	2.945	3.464	2.401	2.826	2.93	3.448	5.659	6.658	5.003	5.886	ns
12 mA	slow	3.417	4.02	2.807	3.303	3.401	4.002	6.083	7.156	5.464	6.428	ns
	medium	3.076	3.618	2.519	2.964	3.063	3.604	5.828	6.856	5.176	6.089	ns
	medium_fast	2.913	3.427	2.376	2.795	2.898	3.41	5.725	6.736	5.072	5.966	ns
	fast	2.894	3.405	2.362	2.78	2.879	3.388	5.715	6.724	5.064	5.957	ns
16 mA	slow	3.366	3.96	2.751	3.237	3.348	3.939	6.226	7.324	5.576	6.56	ns
	medium	3.03	3.565	2.47	2.906	3.017	3.55	5.981	7.036	5.282	6.214	ns
	medium_fast	2.87	3.377	2.328	2.739	2.854	3.358	5.895	6.935	5.18	6.094	ns
	fast	2.853	3.357	2.314	2.723	2.837	3.338	5.889	6.929	5.177	6.09	ns

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO management).

### 2.3.7 Differential I/O Standards

Configuration of the I/O modules as a differential pair is handled by Microsemi SoC Products Group Libero software when the user instantiates a differential I/O macro in the design. Differential I/Os can also be used in conjunction with the embedded Input register (InReg), Output register (OutReg), Enable register (EnReg), and Double Data Rate registers (DDR).

#### 2.3.7.1 LVDS

Low-Voltage Differential Signaling (ANSI/TIA/EIA-644) is a high-speed, differential I/O standard.

##### Minimum and Maximum Input and Output Levels

**Table 160 • LVDS Recommended DC Operating Conditions**

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Supply voltage	$V_{DDI}$	2.375	2.5	2.625	V	2.5 V range
Supply voltage	$V_{DDI}$	3.15	3.3	3.45	V	3.3 V range

**Table 161 • LVDS DC Input Voltage Specification**

Parameter	Symbol	Min	Max	Unit	Conditions
DC Input voltage	$V_I$	0	2.925	V	2.5 V range
DC input voltage	$V_I$	0	3.45	V	3.3 V range
Input current high <sup>1</sup>	$I_{IH}$ (DC)				
Input current low <sup>1</sup>	$I_{IL}$ (DC)				

1. See Table 24, page 22.

### 2.3.7.2 B-LVDS

Bus LVDS (B-LVDS) specifications extend the existing LVDS standard to high-performance multipoint bus applications. Multidrop and multipoint bus configurations may contain any combination of drivers, receivers, and transceivers.

#### Minimum and Maximum DC/AC Input and Output Levels Specification

**Table 173 • B-LVDS Recommended DC Operating Conditions**

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	$V_{DDI}$	2.375	2.5	2.625	V

**Table 174 • B-LVDS DC Input Voltage Specification**

Parameter	Symbol	Min	Max	Unit
DC input voltage	$V_I$	0	2.925	V
Input current high <sup>1</sup>	$I_{IH}$ (DC)			
Input current low <sup>1</sup>	$I_{IL}$ (DC)			

1. See Table 24, page 22.

**Table 175 • B-LVDS DC Output Voltage Specification (for MSIO I/O Bank Only)**

Parameter	Symbol	Min	Typ	Max	Unit
DC output logic high	$V_{OH}$	1.25	1.425	1.6	V
DC output logic low	$V_{OL}$	0.9	1.075	1.25	V

**Table 176 • B-LVDS DC Differential Voltage Specification**

Parameter	Symbol	Min	Max	Unit
Differential output voltage swing (for MSIO I/O bank only)	$V_{OD}$	65	460	mV
Output common mode voltage (for MSIO I/O bank only)	$V_{OCM}$	1.1	1.5	V
Input common mode voltage	$V_{ICM}$	0.05	2.4	V
Input differential voltage	$V_{ID}$	0.1	$V_{DDI}$	V

**Table 177 • B-LVDS Minimum and Maximum AC Switching Speed**

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for MSIO I/O bank)	$D_{MAX}$	500	Mbps	AC loading: 2 pF / 100 $\Omega$ differential load

**Table 178 • B-LVDS AC Impedance Specifications**

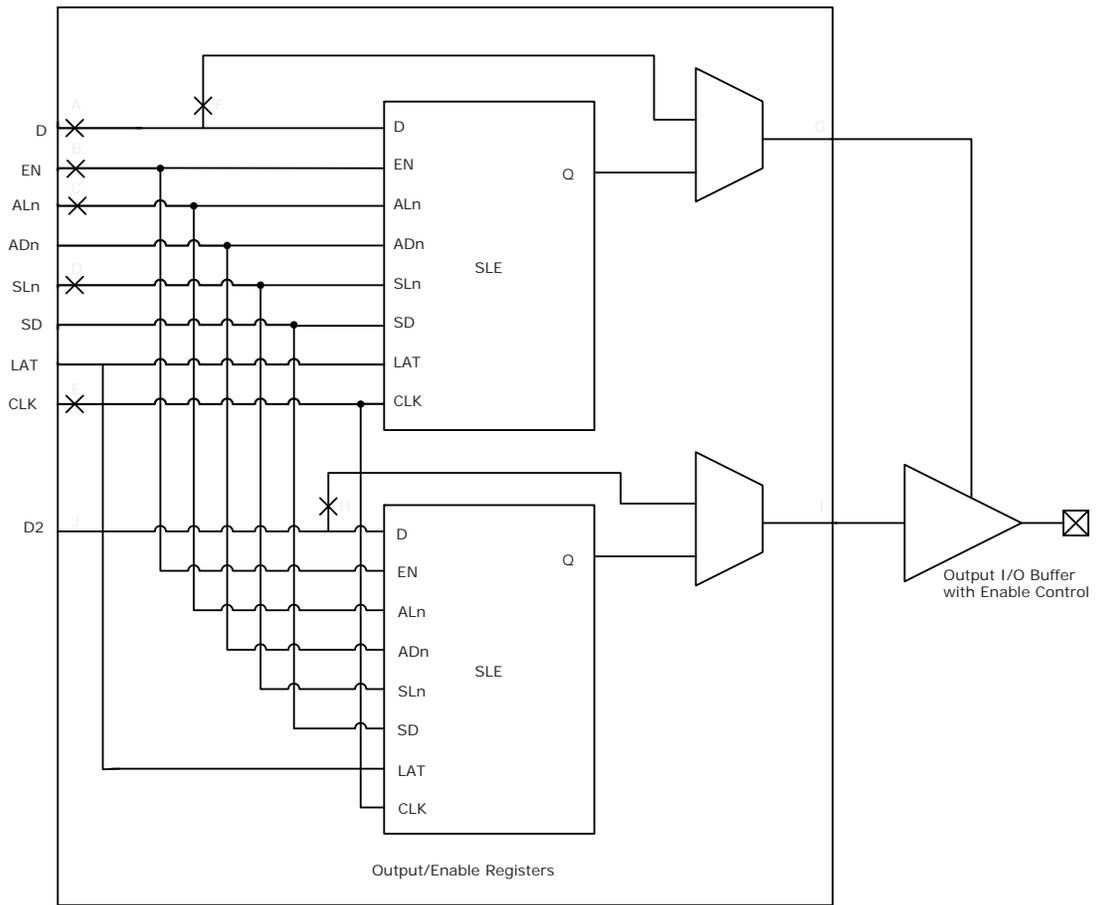
Parameter	Symbol	Typ	Unit
Termination resistance	$R_T$	27	$\Omega$

**Table 179 • B-LVDS AC Test Parameter Specifications**

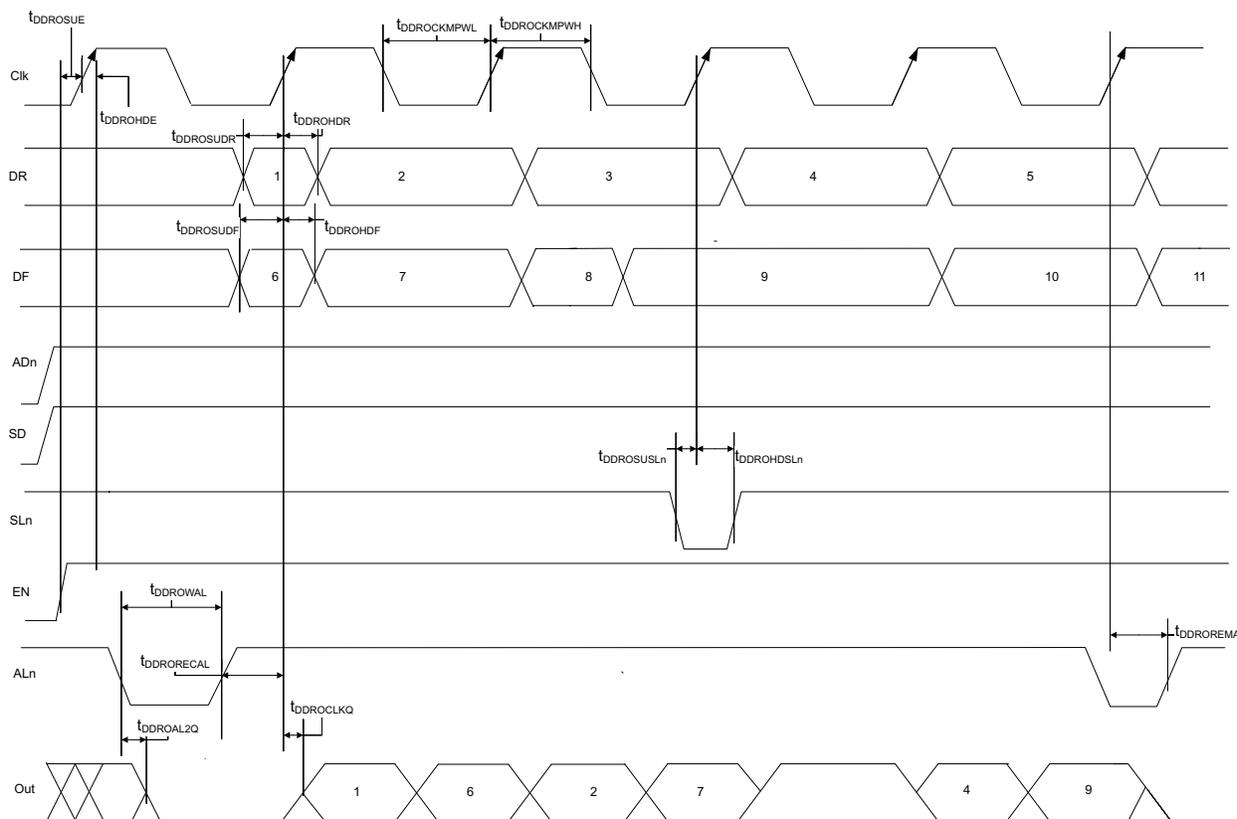
Parameter	Symbol	Typ	Unit
Measuring/trip point for data path	$V_{TRIP}$	Cross point	V
Resistance for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )	$R_{ENT}$	2K	$\Omega$
Capacitive loading for enable path ( $T_{ZH}$ , $T_{ZL}$ , $T_{HZ}$ , $T_{LZ}$ )	$C_{ENT}$	5	pF

### 2.3.8.2 Output/Enable Register

Figure 8 • Timing Model for Output/Enable Register



**Figure 13 • Output DDR Timing Diagram**



**2.3.9.5 Timing Characteristics**

The following table lists the output DDR propagation delays in worst commercial-case conditions when  $T_J = 85^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 222 • Output DDR Propagation Delays**

Symbol	Description	Measuring Nodes (from, to)	-1	-Std	Unit
$T_{DDROCLKQ}$	Clock-to-out of DDR for output DDR	E, G	0.263	0.309	ns
$T_{DDROSUDF}$	Data_F data setup for output DDR	F, E	0.143	0.168	ns
$T_{DDROSUDR}$	Data_R data setup for output DDR	A, E	0.19	0.223	ns
$T_{DDROHDF}$	Data_F data hold for output DDR	F, E	0	0	ns
$T_{DDROHDR}$	Data_R data hold for output DDR	A, E	0	0	ns
$T_{DDROSUE}$	Enable setup for input DDR	B, E	0.419	0.493	ns
$T_{DDROHE}$	Enable hold for input DDR	B, E	0	0	ns
$T_{DDROSUSLn}$	Synchronous load setup for input DDR	D, E	0.196	0.231	ns
$T_{DDROHSLn}$	Synchronous load hold for input DDR	D, E	0	0	ns
$T_{DDROAL2Q}$	Asynchronous load-to-out for output DDR	C, G	0.528	0.621	ns
$T_{DDROREMA}$	Asynchronous load removal time for output DDR	C, E	0	0	ns
$T_{DDRORECAL}$	Asynchronous load recovery time for output DDR	C, E	0.034	0.04	ns

The following table lists the 010 device global resources in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 229 • 010 Device Global Resource**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Input low delay for global clock	$T_{RCKL}$	0.626	0.669	0.627	0.668	ns
Input high delay for global clock	$T_{RCKH}$	1.112	1.182	1.308	1.393	ns
Maximum skew for global clock	$T_{RCKSW}$		0.07		0.085	ns

The following table lists the 005 device global resources in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 230 • 005 Device Global Resource**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Input low delay for global clock	$T_{RCKL}$	0.625	0.66	0.628	0.66	ns
Input high delay for global clock	$T_{RCKH}$	1.126	1.187	1.325	1.397	ns
Maximum skew for global clock	$T_{RCKSW}$		0.061		0.072	ns

## 2.3.12 FPGA Fabric SRAM

See *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide* for more information.

### 2.3.12.1 FPGA Fabric Large SRAM (LSRAM)

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 1K × 18 in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 231 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 1K × 18**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Clock period	$T_{CY}$	2.5		2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125		1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125		1.323		ns
Pipelined clock period	$T_{PLCY}$	2.5		2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125		1.323		ns
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125		1.323		ns
Read access time with pipeline register				0.334	0.393	ns
Read access time without pipeline register	$T_{CLK2Q}$			2.273	2.674	ns
Access time with feed-through write timing				1.529	1.799	ns
Address setup time	$T_{ADDRSU}$	0.441		0.519		ns
Address hold time	$T_{ADDRHD}$	0.274		0.322		ns
Data setup time	$T_{DSU}$	0.341		0.401		ns
Data hold time	$T_{DHD}$	0.107		0.126		ns
Block select setup time	$T_{BLKSU}$	0.207		0.244		ns

The following table lists the RAM1K18 – dual-port mode for depth × width configuration 16K × 1 in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 235 • RAM1K18 – Dual-Port Mode for Depth × Width Configuration 16K × 1**

Parameter	Symbol	–1		–Std		Unit
		Min	Max	Min	Max	
Clock period	$T_{CY}$	2.5		2.941		ns
Clock minimum pulse width high	$T_{CLKMPWH}$	1.125		1.323		ns
Clock minimum pulse width low	$T_{CLKMPWL}$	1.125		1.323		ns
Pipelined clock period	$T_{PLCY}$	2.5		2.941		ns
Pipelined clock minimum pulse width high	$T_{PLCLKMPWH}$	1.125		1.323		ns
Pipelined clock minimum pulse width low	$T_{PLCLKMPWL}$	1.125		1.323		ns
Read access time with pipeline register			0.32		0.377	ns
Read access time without pipeline register	$T_{CLK2Q}$		2.269		2.669	ns
Access time with feed-through write timing			1.51		1.777	ns
Address setup time	$T_{ADDRSU}$	0.626		0.737		ns
Address hold time	$T_{ADDRHD}$	0.274		0.322		ns
Data setup time	$T_{DSU}$	0.322		0.378		ns
Data hold time	$T_{DHD}$	0.082		0.096		ns
Block select setup time	$T_{BLKSU}$	0.207		0.244		ns
Block select hold time	$T_{BLKHD}$	0.216		0.254		ns
Block select to out disable time (when pipelined register is disabled)	$T_{BLK2Q}$		1.51		1.777	ns
Block select minimum pulse width	$T_{BLKMPW}$	0.186		0.219		ns
Read enable setup time	$T_{RDESU}$	0.53		0.624		ns
Read enable hold time	$T_{RDEHD}$	0.071		0.083		ns
Pipelined read enable setup time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLESU}$	0.248		0.291		ns
Pipelined read enable hold time (A_DOUT_EN, B_DOUT_EN)	$T_{RDPLEHD}$	0.102		0.12		ns
Asynchronous reset to output propagation delay	$T_{R2Q}$		1.547		1.82	ns
Asynchronous reset removal time	$T_{RSTREM}$	0.506		0.595		ns
Asynchronous reset recovery time	$T_{RSTREC}$	0.004		0.005		ns
Asynchronous reset minimum pulse width	$T_{RSTMPW}$	0.301		0.354		ns
Pipelined register asynchronous reset removal time	$T_{PLRSTREM}$	–0.279		–0.328		ns
Pipelined register asynchronous reset recovery time	$T_{PLRSTREC}$	0.327		0.385		ns
Pipelined register asynchronous reset minimum pulse width	$T_{PLRSTMPW}$	0.282		0.332		ns
Synchronous reset setup time	$T_{SRSTSU}$	0.226		0.265		ns
Synchronous reset hold time	$T_{SRSTHD}$	0.036		0.043		ns
Write enable setup time	$T_{WESU}$	0.454		0.534		ns
Write enable hold time	$T_{WEHD}$	0.048		0.057		ns
Maximum frequency	$F_{MAX}$		400		340	MHz

**Table 237 •  $\mu$ SRAM (RAM64x18) in 64 × 18 Mode (continued)**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Write address setup time	$T_{ADDRCSU}$	0.088		0.104		ns
Write address hold time	$T_{ADDRCHD}$	0.128		0.15		ns
Write enable setup time	$T_{WECSU}$	0.397		0.467		ns
Write enable hold time	$T_{WECHD}$	-0.026		-0.03		ns
Maximum frequency	$F_{MAX}$		250		250	MHz

The following table lists the  $\mu$ SRAM in 64 × 16 mode in worst commercial-case conditions when  $T_J = 85\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 238 •  $\mu$ SRAM (RAM64x16) in 64 × 16 Mode**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Read clock period	$T_{CY}$	4		4		ns
Read clock minimum pulse width high	$T_{CLKMPWH}$	1.8		1.8		ns
Read clock minimum pulse width low	$T_{CLKMPWL}$	1.8		1.8		ns
Read pipeline clock period	$T_{PLCY}$	4		4		ns
Read pipeline clock minimum pulse width high	$T_{PLCLKMPWH}$	1.8		1.8		ns
Read pipeline clock minimum pulse width low	$T_{PLCLKMPWL}$	1.8		1.8		ns
Read access time with pipeline register	$T_{CLK2Q}$		0.266		0.313	ns
Read access time without pipeline register				1.677		1.973
Read address setup time in synchronous mode	$T_{ADDRSU}$	0.301		0.354		ns
Read address setup time in asynchronous mode			1.856		2.184	
Read address hold time in synchronous mode	$T_{ADDRHD}$	0.091		0.107		ns
Read address hold time in asynchronous mode			-0.778		-0.915	
Read enable setup time	$T_{RDENSU}$	0.278		0.327		ns
Read enable hold time	$T_{RDENHD}$	0.057		0.067		ns
Read block select setup time	$T_{BLKSU}$	1.839		2.163		ns
Read block select hold time	$T_{BLKHD}$	-0.65		-0.765		ns
Read block select to out disable time (when pipelined register is disabled)	$T_{BLK2Q}$		2.036		2.396	ns
Read asynchronous reset removal time (pipelined clock)	$T_{RSTREM}$	-0.023		-0.027		ns
Read asynchronous reset removal time (non-pipelined clock)			0.046		0.054	
Read asynchronous reset recovery time (pipelined clock)	$T_{RSTREC}$	0.507		0.597		ns
Read asynchronous reset recovery time (non-pipelined clock)			0.236		0.278	
Read asynchronous reset to output propagation delay (with pipelined register enabled)	$T_{R2Q}$		0.835		0.983	ns
Read synchronous reset setup time	$T_{SRSTSU}$	0.271		0.319		ns

**Table 240 •  $\mu$ SRAM (RAM128x8) in 128 x 8 Mode (continued)**

Parameter	Symbol	-1		-Std		Unit
		Min	Max	Min	Max	
Read address hold time in synchronous mode	$T_{ADDRHD}$	0.091		0.107		ns
Read address hold time in asynchronous mode		-0.778		-0.915		ns
Read enable setup time	$T_{RDENSU}$	0.278		0.327		ns
Read enable hold time	$T_{RDENHD}$	0.057		0.067		ns
Read block select setup time	$T_{BLKSU}$	1.839		2.163		ns
Read block select hold time	$T_{BLKHD}$	-0.65		-0.765		ns
Read block select to out disable time (when pipelined register is disabled)	$T_{BLK2Q}$		2.036		2.396	ns
Read asynchronous reset removal time (pipelined clock)	$T_{RSTREM}$	-0.023		-0.027		ns
Read asynchronous reset removal time (non-pipelined clock)		0.046		0.054		ns
Read asynchronous reset recovery time (pipelined clock)	$T_{RSTREC}$	0.507		0.597		ns
Read asynchronous reset recovery time (non-pipelined clock)		0.236		0.278		ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	$T_{R2Q}$		0.835		0.982	ns
Read synchronous reset setup time	$T_{SRSTSU}$	0.271		0.319		ns
Read synchronous reset hold time	$T_{SRSTHD}$	0.061		0.071		ns
Write clock period	$T_{CCY}$	4		4		ns
Write clock minimum pulse width high	$T_{CCLKMPWH}$	1.8		1.8		ns
Write clock minimum pulse width low	$T_{CCLKMPWL}$	1.8		1.8		ns
Write block setup time	$T_{BLKCSU}$	0.404		0.476		ns
Write block hold time	$T_{BLKCHD}$	0.007		0.008		ns
Write input data setup time	$T_{DINCSU}$	0.115		0.135		ns
Write input data hold time	$T_{DINCHD}$	0.15		0.177		ns
Write address setup time	$T_{ADDRCSU}$	0.088		0.104		ns
Write address hold time	$T_{ADDRCHD}$	0.128		0.15		ns
Write enable setup time	$T_{WECSU}$	0.397		0.467		ns
Write enable hold time	$T_{WECHD}$	-0.026		-0.03		ns
Maximum frequency	$F_{MAX}$		250		250	MHz

1. The minimum output clock frequency is limited by the PLL. For more information, see *UG0449: SmartFusion2 and IGLOO2 Clocking Resources User Guide*.
2. The PLL is used in conjunction with the Clock Conditioning Circuitry. Performance is limited by the CCC output frequency.

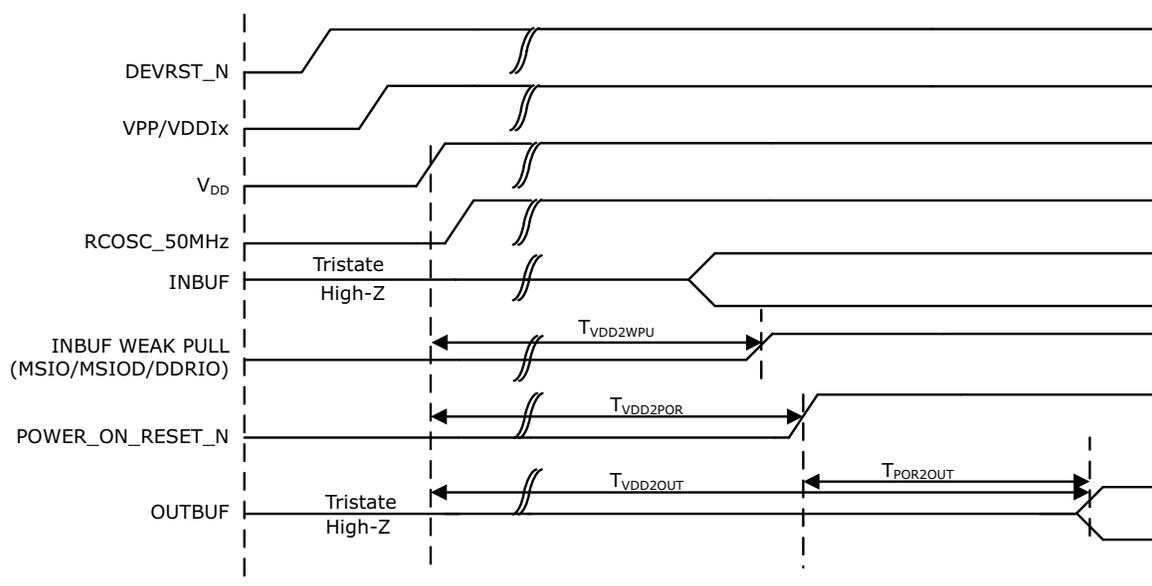
The following table lists the CCC/PLL jitter specifications in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 283 • IGLOO2 and SmartFusion2 SoC FPGAs CCC/PLL Jitter Specifications**

CCC Output Maximum Peak-to-Peak Period Jitter $F_{OUT\_CCC}$						
Parameter	Conditions/Package Combinations				Unit	
<b>10 FG484, 050 FG896/FG484/FCS325 Packages<sup>1</sup></b>	SSO = 0	0 < SSO <= 2	SSO <= 4	SSO <= 8	SSO <= 16	
20 MHz to 100 MHz	Max(110, $\pm 1\% \times (1/F_{OUT\_CCC})$ )	Max(150, $\pm 1\% \times (1/F_{OUT\_CCC})$ )				ps
100 MHz to 400 MHz	Max(120, $\pm 1\% \times (1/F_{OUT\_CCC})$ )	Max(150, $\pm 1\% \times (1/F_{OUT\_CCC})$ )		Max(170, $\pm 1\% \times (1/F_{OUT\_CCC})$ )		ps
<b>025 FG484/FCS325 Package<sup>1</sup></b>	0 < SSO <=16					
20 MHz to 74 MHz	$\pm 1\% \times (1/F_{OUT\_CCC})$					ps
74 MHz to 400 MHz	210					ps
<b>005 FG484 Package<sup>1</sup></b>	0 < SSO <=16					
20 MHz to 53 MHz	$\pm 1\% \times (1/F_{OUT\_CCC})$					ps
53 MHz to 400 MHz	270					ps
<b>090 FG676 and FC325 Package<sup>1</sup></b>	0 < SSO <=16					
20 MHz to 100 MHz	$\pm 1\% \times (1/F_{OUT\_CCC})$					ps
100 MHz to 400 MHz	150					ps
<b>060 FG676 Package<sup>1</sup></b>	0 < SSO <=16					
20 MHz to 100 MHz	$\pm 1\% \times (1/F_{OUT\_CCC})$					ps
100 MHz to 400 MHz	150					ps
<b>150 FC1152 Package<sup>1</sup></b>	0 < SSO <=16					
20 MHz to 100 MHz	$\pm 1\% \times (1/F_{OUT\_CCC})$					ps
100 MHz to 400 MHz	120					ps

1. SSO data is based on LVCMOS 2.5 V MSIO and/or MSIOD bank I/Os.

Figure 18 • Power-up to Functional Timing Diagram for IGLOO2



### 2.3.25 DEVRST\_N Characteristics

Table 290 • DEVRST\_N Characteristics for All Devices

Parameter	Symbol	Max	Unit
DEVRST_N ramp rate	$T_{RAMPDEVRSTN}$	1	us
DEVRST_N cycling rate	$F_{MAXPDEVRSTN}$	100	kHz

### 2.3.26 DEVRST\_N to Functional Times

The following table lists the SmartFusion2 DEVRST\_N to functional times in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

Table 291 • DEVRST\_N to Functional Times for SmartFusion2

Symbol	From	To	Description	Maximum Power-up to Functional Time for SmartFusion2 (uS)						
				005	010	025	050	060	090	150
$T_{POR2OUT}$	POWER_ON_RESET_N	Output available at I/O	Fabric to output	518	501	527	521	422	419	694
$T_{POR2MSSRST}$	POWER_ON_RESET_N	MSS_RESET_N_M2F	Fabric to MSS	515	497	524	518	417	414	689
$T_{MSSRST2OUT}$	MSS_RESET_N_M2F	Output available at I/O	MSS to output	3.5	3.5	3.5	3.3	4.8	4.8	4.8
$T_{DEVRST2OUT}$	DEVRST_N	Output available at I/O	$V_{DD}$ at its minimum threshold level to output	706	768	715	691	641	635	871

The following table lists the IGLOO2 DEVRST\_N to functional times in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 292 • DEVRST\_N to Functional Times for IGLOO2**

Symbol	From	To	Description	Maximum Power-up to Functional Time for IGLOO2 (uS)						
				005	010	025	050	060	090	150
$T_{POR2OUT}$	POWER_ON_RESET_N	Output available at I/O	Fabric to output	114	116	113	113	115	115	114
$T_{DEVRST2OUT}$	DEVRST_N	Output available at I/O	$V_{DD}$ at its minimum threshold level to output	314	353	314	307	343	341	341
$T_{DEVRST2POR}$	DEVRST_N	POWER_ON_RESET_N	$V_{DD}$ at its minimum threshold level to fabric	200	238	201	195	230	229	227
$T_{DEVRST2WPU}$	DEVRST_N	DDRIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215
	DEVRST_N	MSIO Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215
	DEVRST_N	MSIOD Inbuf weak pull	DEVRST_N to Inbuf weak pull	208	202	197	193	216	215	215

**Table 293 • Flash\*Freeze Entry and Exit Times (continued)**

Parameter	Symbol	Entry/Exit Timing			Unit	Conditions
		FCLK = 100MHz		FCLK = 3 MHz		
		005, 010, 025, 060, 090, and 150	050	All Devices		
Exit time with respect to the fabric PLL lock <sup>1</sup>	TFF_EXIT	1.5	1.5	1.5	ms	eNVM and MSS/HPMS PLL = ON during F*F
		1.5	1.5	1.5	ms	eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit
Exit time with respect to the fabric buffer output	TFF_EXIT	21	15	21	µs	eNVM and MSS/HPMS PLL = ON during F*F
		65	55	65	µs	eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit

1. PLL Lock Delay set to 1024 cycles (default).

### 2.3.28 DDR Memory Interface Characteristics

The following table lists the DDR memory interface characteristics in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 294 • DDR Memory Interface Characteristics**

Standard	Supported Data Rate		Unit
	Min	Max	
DDR3	667	667	Mbps
DDR2	667	667	Mbps
LPDDR	50	400	Mbps

### 2.3.29 SFP Transceiver Characteristics

IGLOO2 and SmartFusion2 SerDes complies with small form-factor pluggable (SFP) requirements as specified in SFP INF-80741. The following table provides the electrical characteristics.

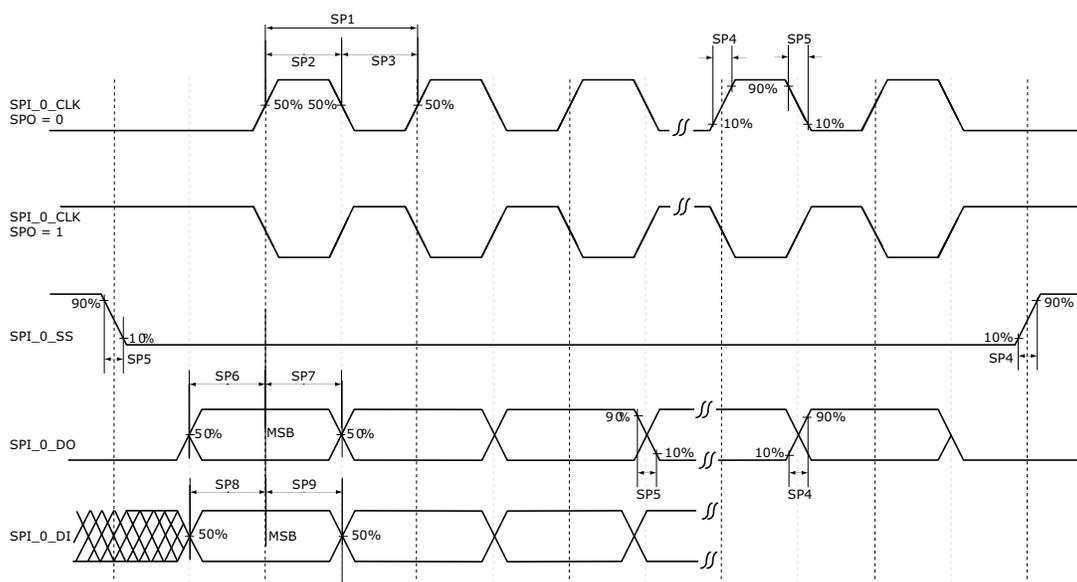
The following table lists the SFP transceiver electrical characteristics in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

**Table 295 • SFP Transceiver Electrical Characteristics**

Pin	Direction	Differential Peak-Peak Voltage		Unit
		Min	Max	
RD+/- <sup>1</sup>	Output	1600	2400	mV
TD+/- <sup>2</sup>	Input	350	2400	mV

1. Based on default SerDes transmitter settings for PCIe Gen1. Lower amplitudes are available through programming changes to TX\_AMP setting.
2. Based on Input Voltage Common-Mode (VICM) = 0 V. Requires AC Coupling.

Figure 22 • SPI Timing for a Single Frame Transfer in Motorola Mode (SPH = 1)



### 2.3.32 CAN Controller Characteristics

The following table lists the CAN controller characteristics in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

Table 306 • CAN Controller Characteristics

Parameter	Description	-1	-Std	Unit
FCANREFCLK <sup>1</sup>	Internally sourced CAN reference clock frequency	160	136	MHz
BAUDCANMAX	Maximum CAN performance baud rate	1	1	Mbps
BAUDCANMIN	Minimum CAN performance baud rate	0.05	0.05	Mbps

1. PCLK to CAN controller must be a multiple of 8 MHz.

### 2.3.33 USB Characteristics

The following table lists the USB characteristics in worst-case industrial conditions when  $T_J = 100\text{ }^\circ\text{C}$ ,  $V_{DD} = 1.14\text{ V}$ .

Table 307 • USB Characteristics

Parameter	Description	-1	-Std	Unit
FUSBREFCLK	Internally sourced USB reference clock frequency	166	142	MHz
TUSBCLK	USB clock period	16.66	16.66	ns
TUSBPD	Clock to USB data propagation delay	9.0	9.0	ns
TUSBSU	Setup time for USB data	6.0	6.0	ns
TUSBHD	Hold time for USB data	0	0	ns